

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC74LCX16245FT**

Low-Voltage 16-Bit Bus Transceiver with 5-V Tolerant Inputs and Outputs

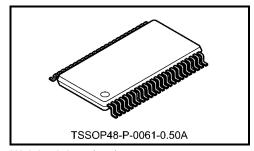
The TC74LCX16245FT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (2.5-V or 3.3-V)  $V_{\rm CC}$  applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable (  $\overline{OE}$  ) inputs which

h are common to each byte. It can be used as two 8-bit transceiver or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The  $\overline{\rm OE}$  inputs can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

#### Features (Note)

- Low-voltage operation: VCC = 2.0 to 3.6 V
- Wide operating temperature range: Topr = -40 to 125 °C (Note 1)
- High-speed operation:  $t_{pd} = 4.5 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: -500 mA
- Package: TSSOP
- Bidirectional interface between 5.0 V and low-voltage (2.5-V or 3.3-V) signals
- · Power-down protection provided on all inputs and outputs

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

Note 1: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.

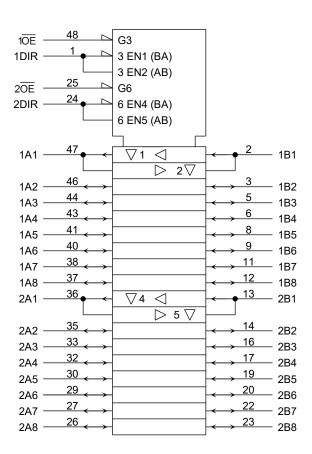
Start of commercial production 2020-04



### Pin Assignment (top view)

#### 1DIR 48 10E 1B1 2 1A1 1B2 3 46 1A2 GND 4 **GND** 45 5 1A3 1B3 1B4 6 1A4 Vcc 42 $V_{CC}$ 1B5 8 1A5 1B6 9 40 1A6 GND 10 39 **GND** 1B7 11 38 1A7 1B8 12 37 1A8 2B1 13 36 2A1 2B2 14 2A2 GND 15 **GND** 2B3 16 33 2A3 2B4 17 32 2A4 V<sub>C</sub>C 18 31 Vcc 2B5 19 30 2A5 2B6 20 29 2A6 **GND** GND 21 28 2B7 22 2A7 2B8 23 2A8 2DIR 24 2OE

### **IEC Logic Symbol**





### **Truth Table**

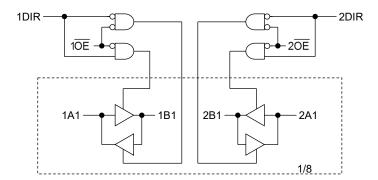
Inp	Inputs		Function		
1 <del>OE</del>	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs	
L	L	Output	Output Input		
L	Н	Input Output		B=A	
Н	Х	2	7	Z	

Inp	Inputs Function		Function		
2 <del>OE</del>	2DIR	Bus 2A1-2A8	Bus 2B1-2B8	Outputs	
L	L	Output	Input	A = B	
L	Н	Input Output		B=A	
Н	Х	2	Z		

X: Don't care

Z: High impedance

## **System Diagram**



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#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 6.0	V
DC input voltage (DIR, $\overline{\text{OE}}$ )	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
DC bus I/O voltage	V <sub>I/O</sub>	$-0.5$ to $V_{CC} + 0.5$ (Note 2)	V
Input diode current	lıĸ	-50	mA
Output diode current	lok	±50 (Note 3)	mA
DC output current	lout	±50	mA
Power dissipation	PD	400 (Note 4)	mW
DC V <sub>CC</sub> /ground current per supply pin	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state

Note 2: High or low state. IOUT absolute maximum rating must be observed.

Note 3: VOUT < GND, VOUT > VCC

Note 4: 400 mW in the range of Ta = -40 to 85 °C. From Ta = 85 to 125 °C a derating factor of -6.25 mW/°C shall be applied until 150 mW.

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Dower cumply veltage	\/	2.0 to 3.6	V
Power supply voltage	Vcc	1.5 to 3.6 (Note 1)	V
Input voltage (DIR, $\overline{\text{OE}}$ )	Vin	0 to 5.5	٧
Bus I/O voltage	V <sub>I/O</sub>	0 to 5.5 (Note 2)	V
Bus I/O voltage	V 1/O	0 to V <sub>CC</sub> (Note 3)	V
		±24 (Note 4)	
Output current	IOH/IOL	±12 (Note 5)	mA
		±8 (Note 6)	
Operating temperature	T <sub>opr</sub>	-40 to 125 (Note 7)	°C
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note 1: Data retention only

Note 2: Output in OFF state

Note 3: High or low state

Note 4: VCC = 3.0 to 3.6 V

Note 5: VCC = 2.7 to 3.0 V

Note 6: VCC = 2.3 to 2.7 V

Note 7: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.

Note 8:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



### **Electrical Characteristics**

### DC Characteristics (Unless otherwise specified, Ta = -40 to 85°C)

Characteris	tion	Cumbal	Test Condition			Min	Max	Unit			
Characterist	lics	Symbol			Test Condition	Vcc (V		yribbi rest condition		V <sub>CC</sub> (V)	IVIII
	H-level	\ /···			2.3 to 2.7	1.7	_				
Input voltage	H-level	VIH	_	_	2.7 to 3.6	2.0	_	V			
iliput voltage	L-level	\/··			2.3 to 2.7	_	0.7	V			
	L-ievei	VIL	_	_	2.7 to 3.6	_	0.8				
				ΙοΗ = -100 μΑ	2.3 to 3.6	V <sub>C</sub> C - 0.2					
			VIN = VIH or VIL	IOH = -8  mA	2.3	1.8					
	H-level	Voн		IOH = -12  mA	2.7	2.2		V			
				IOH = -18  mA	3.0	2.4					
Output voltage				IOH = -24 mA	3.0	2.2					
			VIN = VIH or VIL	IOL = 100 μA	2.3 to 3.6	_	0.2				
				IOL = 8 mA	2.3	_	0.6				
	L-level	VoL		IOL = 12 mA	2.7	_	0.4				
				IOL = 16 mA	3.0	_	0.4				
			I <sub>OL</sub> = 24 mA	3.0	_	0.55					
Input leakage current		liN	V <sub>IN</sub> = 0 to 5.5 V		2.3 to 3.6	_	±5.0	μΑ			
3-state output OFF state current		loz	VIN = VIH or VIL VOUT = 0 to 5.5 V		2.3 to 3.6	_	±5.0	μА			
Power-off leakage cur	rent	IOFF	VIN/VOUT = 5.5 V		0	_	10.0	μΑ			
Quiescent supply curr	Ouis a sant summit summent		V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 3.6	_	20.0				
Quiescent supply cult		Icc	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.3 to 3.6	_	±20.0	μΑ			
Increase in ICC per inp	out	Δlcc	VIH = VCC - 0.6 V		2.3 to 3.6	_	500				



## DC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 125°C)

Characteristics		Symbol	Test Condition Min M		Max	Unit								
Ondradional	100	Cymbol	165t Cornalion		Vcc (V)	141111		OTHE						
	H-level	VIH			2.3 to 2.7	1.7								
lanut valtaga	n-ievei	VIH		-	2.7 to 3.6	2.0	_	V						
Input voltage	L-level	VIL			2.3 to 2.7	_	0.7	V						
	L-level	VIL		-	2.7 to 3.6	_	8.0							
				I <sub>OH</sub> = -100 μA	2.3 to 3.6	V <sub>C</sub> C - 0.2	_							
				$I_{OH} = -8 \text{ mA}$	2.3	1.55	_							
	H-level	VoH	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -12 mA	2.7	2.0	_	V						
				I <sub>OH</sub> = -18 mA	3.0	2.2	_							
Output voltage				I <sub>OH</sub> = -24 mA	3.0	1.9	_							
			VIN = VIH or VIL	I <sub>OL</sub> = 100 μA	2.3 to 3.6	_	0.2							
	L-level Vo			I <sub>OL</sub> = 8 mA	2.3	_	0.9							
		Vol		IOL = 12 mA	2.7	_	0.6							
							l			I <sub>O</sub> L = 16 mA	IOL = 16 mA	3.0	_	0.6
			I <sub>OL</sub> = 24 mA		3.0	_	8.0							
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		2.3 to 3.6	_	±20.0	μА						
3-state output OFF state current		loz	VIN = VIH or VIL VOUT = 0 to 5.5 V		2.3 to 3.6	_	±20.0	μΑ						
Power-off leakage curr	ent	loff	VIN/VOUT = 5.5 V		0	_	40.0	μΑ						
Quiescent supply curre		loo	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 3.6	_	80.0							
Quiescent supply curre		Icc	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.3 to 3.6	_	±80.0	μΑ						
Increase in ICC per inp	out	Δlcc	VIH = VCC - 0.6 V		2.3 to 3.6	_	5000							

Note: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.



### AC Characteristics (Unless otherwise specified, Ta = -40 to 85°C)

Chana stanistica	Symbol Test Condition				Min	May	Unit
Characteristics	Symbol	rest Condition	Vcc (V)	CL(pF)	IVIIN	Max	Unit
	_		$2.5 \pm 0.2$	30	1.5	5.4	
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2	2.7	50	1.5	5.2	ns
	pric		$3.3 \pm 0.3$	50	1.5	4.5	
			$2.5\pm0.2$	30	1.5	8.5	
3-state output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 3	2.7	50	1.5	7.2	ns
			$3.3 \pm 0.3$	50	1.5	6.5	
			$2.5\pm0.2$	30	1.5	7.7	
3-state output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	Figure 1, Figure 3	2.7	50	1.5	6.9	ns
	ψηΖ		$3.3\pm0.3$	50	1.5	6.0	
Output to output skew			$2.5 \pm 0.2$	30	_	_	
	t <sub>osLH</sub> t <sub>osHL</sub>	(Note)	2.7	50	_	_	ns
		-	$3.3\pm0.3$	50	_	1.0	

Note: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

### AC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 125°C)

Characteristics	Cumala al	Symbol Test Condition			Min	May	l lmi4
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	CL(pF)	IVIIN	Max	Unit
	_		2.5 ± 0.2	30	1.5	5.9	
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2	2.7	50	1.5	5.7	ns
	·pπ∟		$3.3\pm0.3$	50	1.5	4.9	
			$2.5\pm0.2$	30	1.5	9.4	
3-state output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 3	2.7	50	1.5	8.0	ns
			$3.3 \pm 0.3$	50	1.5	7.2	
			$2.5\pm0.2$	30	1.5	8.5	
3-state output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	Figure 1, Figure 3	2.7	50	1.5	7.6	ns
	φιιΖ		$3.3 \pm 0.3$	50	1.5	6.6	
Output to output skew	_		2.5 ± 0.2	30	_	_	
	tosLH tosHL	(Note1	) 2.7	50	_	_	ns
			3.3 ± 0.3	50	_	1.0	

Note: Operating Range spec of Topr= -40 °C to 125 °C is applicable only for the products which manufactured after April 2020.

Note 1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)



### **Dynamic Switching Characteristics**

(Ta = 25°C, input:  $t_r = t_f = 2.5$  ns,  $R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	Volp	V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V, C <sub>L</sub> =30pF	2.5	0.6	V
	VOLP	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V, C <sub>L</sub> =50pF	3.3	0.8	v
Quiet output minimum	Mand	V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V, C <sub>L</sub> =30pF	2.5	0.6	V
dynamic V <sub>OL</sub>	Volv	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V, C <sub>L</sub> =50pF	3.3	8.0	]

### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>	_	3.3	7	pF
Bus input capacitance	C <sub>I/O</sub>	_	3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	$f_{IN} = 10 \text{ MHz}$ (No	te) 3.3	25	pF

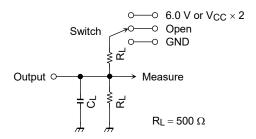
Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) =  $CPD \cdot VCC \cdot fIN + ICC/16$  (per bit)



#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	6.0 V V <sub>CC</sub> × 2	$@V_{CC} = 3.3 \pm 0.3 \text{ V} \\ @V_{CC} = 2.5 \pm 0.2 \text{ V}$	
t <sub>pHZ</sub> , t <sub>pZH</sub>		GND	

Figure 1

#### **AC Waveform**

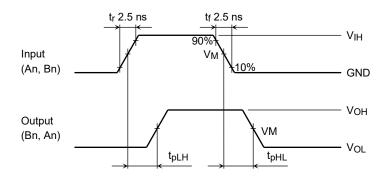


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

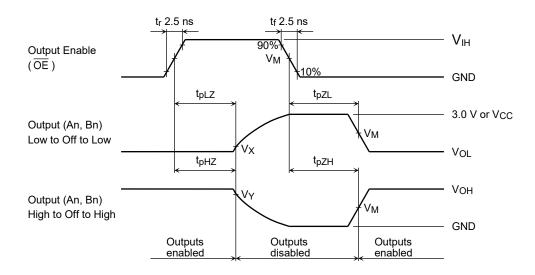


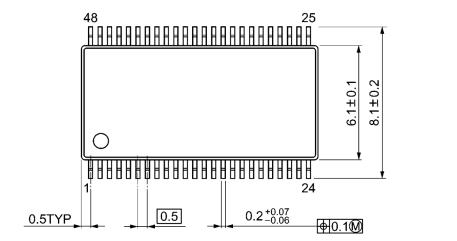
Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

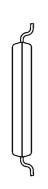
Cumhal	Vcc						
Symbol	$3.3\pm0.3~\textrm{V}$	2.7 V	$2.5\pm0.2\textrm{V}$				
VIH	2.7 V	2.7 V	Vcc				
VM	1.5 V	1.5 V	Vcc/2				
Vx	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V				
VY	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.15 V				

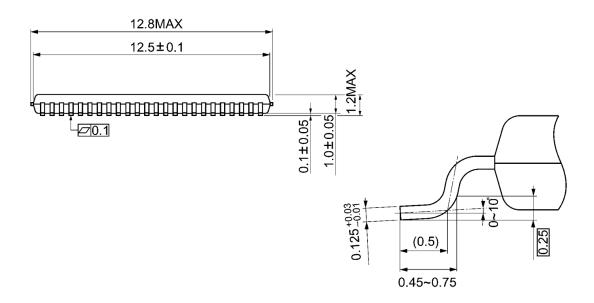


### **Package Dimensions**

TSSOP48-P-0061-0.50A Unit: mm







Weight: 0.25 g (typ.)

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